

Dear Customer,

With this INFINEON Technologies Errata Note we would like to inform you about the following

Update of AN2018-09 „Guidelines for CoolSiC™ MOSFET gate drive voltage window” referred to in the footnote of SiC MOSFET module datasheets

ERRATA



N° 10192AERRA

Update of AN2018-09 „Guidelines for CoolSiC™ MOSFET gate drive voltage window” referred to in the footnote of SiC MOSFET module datasheets

► **Products affected:** Please refer to attached affected product list 1_cip10192_a

► **Detailed Change Information:**

Subject: The datasheets refer to the AN2018-09 via footnote. The AN2018-09 has been updated. The datasheets have not been changed.

Reason: The impact of over- and undershoots is described in more detail in AN2018-09.

Description:	<u>Old</u>	<u>New</u>
	<ul style="list-style-type: none">■ AN2018-09 Initial version 1.0.	<ul style="list-style-type: none">■ AN2018-09 Revision 1.1: Including the undershoot/overshoot in the ROA, and modify corresponding wording.

► **Impact of Change:** Gate drive voltage selection depends on operation conditions.

► **Attachments:** Affected product list 1_cip10192_a



► **Implementation Date:** With immediate effect.

If you have any questions, please do not hesitate to contact your local Sales office.